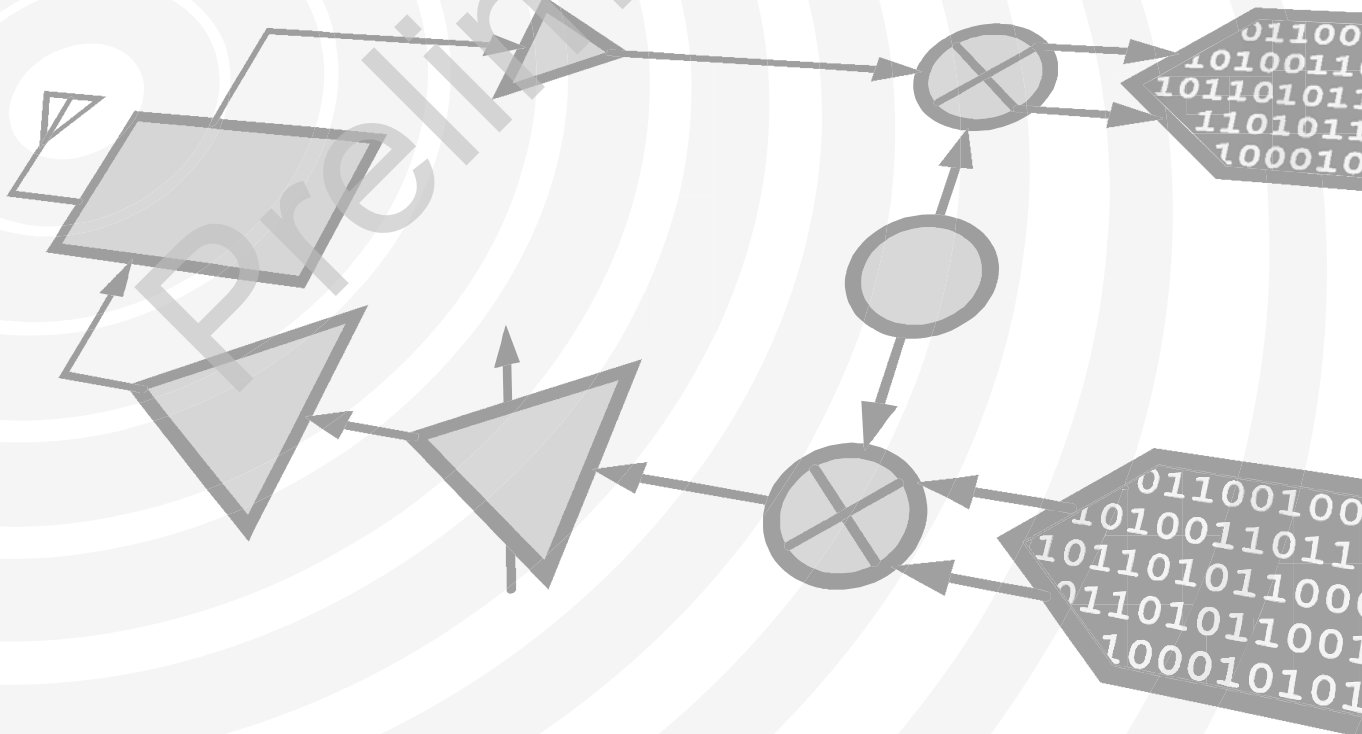


Analog Devices Welcomes Hittite Microwave Corporation



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Preliminary

0.5 dB LSB GaAs MMIC 6-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, 2.2 - 8.0 GHz

Typical Applications

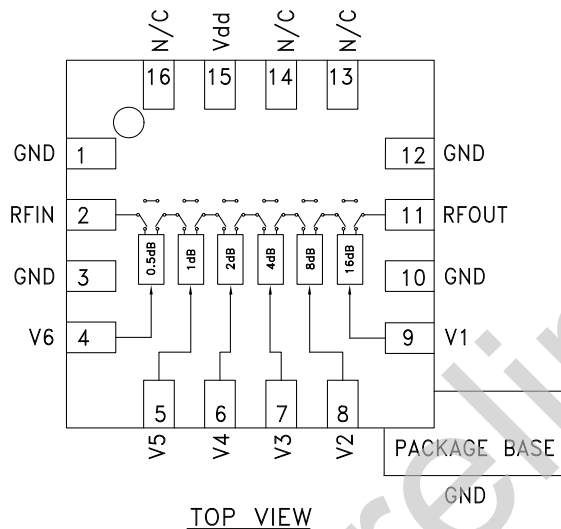
The HMC425ALP3 / HMC425ALP3E is ideal for:

- WLAN & Point-to-Multi-Point
- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military

Features

- 0.5 dB LSB Steps to 31.5 dB
- Single Control Line Per Bit
- ± 0.5 dB Typical Bit Error
- Single +5V Supply
- 3x3 mm SMT Package

Functional Diagram



General Description

The HMC425ALP3 & HMC425ALP3E are broadband 6-bit GaAs IC digital attenuators in low cost leadless surface mount packages. Covering 2.2 to 8.0 GHz, the insertion loss is less than 3.8 dB typical. The attenuator bit values are 0.5 (LSB), 1, 2, 4, 8, and 16 dB for a total attenuation of 31.5 dB. Attenuation accuracy is excellent at ± 0.5 dB typical step error with an IIP3 of +40 dBm. Six control voltage inputs, toggled between 0 and +3 to +5V, are used to select each attenuation state. A single Vdd bias of +3 to +5V is required.

Electrical Specifications,

$T_A = +25^\circ \text{C}$, With $V_{dd} = +5\text{V}$ & $V_{ctl} = 0/+5\text{V}$ (Unless Otherwise Noted)

Parameter	Frequency (GHz)	Min.	Typ.	Max.	Units
Insertion Loss	2.2 - 6.0 GHz 6.0 - 8.0 GHz		3.5 3.8	3.8 4.3	dB dB
Attenuation Range	2.2 - 8.0 GHz		31.5		dB
Return Loss (RF1 & RF2, All Atten. States)	2.2 - 8.0 GHz		15		dB
Attenuation Accuracy: (Referenced to Insertion Loss)	All States 2.2 - 8.0 GHz	$\pm 0.5 + 5\%$ of Atten. Setting Max.			dB
Input Power for 0.1 dB Compression	$V_{dd} = 5\text{V}$ $V_{dd} = 3\text{V}$ 2.2 - 8.0 GHz		22 19		dBm dBm
Input Third Order Intercept Point (Two-Tone Input Power= 0 dBm Each Tone)	REF - 16.0 dB States 16.5 - 31.5 dB States 2.2 - 8.0 GHz		45 35		dBm dBm
Switching Characteristics	2.2 - 8.0 GHz				
tRISE, tFALL (10/90% RF)			160		ns
tON, tOFF (50% CTL to 10/90% RF)			180		ns

**0.5 dB LSB GaAs MMIC 6-BIT DIGITAL
POSITIVE CONTROL ATTENUATOR, 2.2 - 8.0 GHz**
Absolute Maximum Ratings

Control Voltage (V1 to V6)	Vdd +0.5 Vdc
Bias Voltage (Vdd)	+7.0 Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
RF Input Power (2.4 - 8.0 GHz)	+30 dBm
ESD Sensitivity (HBM)	Class 1A



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Truth Table

Control Voltage Input						Attenuation State RF1 - RF2
V1 16 dB	V2 8 dB	V3 4 dB	V4 2 dB	V5 1 dB	V6 0.5 dB	
High	High	High	High	High	High	Reference I.L.
High	High	High	High	High	Low	0.5 dB
High	High	High	High	Low	High	1 dB
High	High	High	Low	High	High	2 dB
High	High	Low	High	High	High	4 dB
High	Low	High	High	High	High	8 dB
Low	High	High	High	High	High	16 dB
Low	Low	Low	Low	Low	Low	31.5 dB

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

Outline Drawing
